



## UNITED STATES PATENT AND TRADEMARK OFFICE

UNITED STATES DEPARTMENT OF COMMERCE  
United States Patent and Trademark Office  
Address: COMMISSIONER FOR PATENTS  
P.O. Box 1450  
Alexandria, Virginia 22313-1450  
www.uspto.gov

## \*BIBDATASHEET\*

CONFIRMATION NO. 7058

Bib Data Sheet

SERIAL NUMBER 10/618,688	FILING DATE 07/15/2003  RULE	CLASS 438	GROUP ART UNIT 2824	ATTORNEY DOCKET NO. 110405.01
-----------------------------	---------------------------------------	--------------	------------------------	-------------------------------------

## APPLICANTS

Eiji Natori, Chino-shi, JAPAN;

Kazumasa Hasegawa, Fujimi-cho, JAPAN;

Koichi Oguchi, Suwa-shi, JAPAN; Takao Nishikawa, Shiojiri-shi, JAPAN;

Tatsuya Shimoda, Fujimi-cho, JAPAN;

## \*\* CONTINUING DATA \*\*\*\*\*



This application is a DIV of 09/931,915 08/20/2001 PAT 6,617,627 CDW

## \*\* FOREIGN APPLICATIONS \*\*\*\*\*

JAPAN 2000-251436 08/22/2000 CDW

## IF REQUIRED, FOREIGN FILING LICENSE GRANTED

\*\* 10/14/2003

Foreign Priority claimed <input checked="" type="checkbox"/> yes <input type="checkbox"/> no	STATE OR	SHEETS	TOTAL	INDEPENDENT
35 USC 119 (a-d) conditions met <input checked="" type="checkbox"/> yes <input type="checkbox"/> no <input type="checkbox"/> Met after Allowance	COUNTRY	DRAWING	CLAIMS	CLAIMS
Verified and Acknowledged Examiner's Signature  Initials 	JAPAN	13	20	3

## ADDRESS

25944

OLIFF &amp; BERRIDGE, PLC

P.O. BOX 19928

ALEXANDRIA, VA

22320

## TITLE

Memory cell array having ferroelectric capacity, method of manufacturing the same and ferroelectric memory device

☐ All Fees